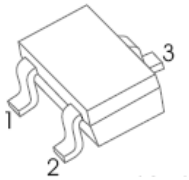
MMBT3904T
NPN TRANSISTOR



1. BASE
2. EMITTER
3. COLLECTOR

FEATURES

for switching and amplifier applications

- Complementary to MMBT3906T
- Small Package

1N

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

MAXIMUM RATINGS (T_a=25℃ unless otherwise noted)

Symbol	Parameter	Value	Unit
V_{CBO}	Collector-Base Voltage	60	V
V_{CEO}	Collector-Emitter Voltage	40	V
V_{EBO}	Emitter-Base Voltage	6	V
I_C	Collector Current	200	mA
P_C	Collector Power Dissipation	150	mW
$R_{\Theta JA}$	Thermal Resistance From Junction To Ambient	833	℃/W
T_j	Junction Temperature	150	℃
T_{stg}	Storage Temperature	-55～+150	℃

Characteristics at T_a = 25 °C

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Collector-base breakdown voltage	$V_{(BR)CBO}$	I_C=10μA, I_E=0	60			V
Collector-emitter breakdown voltage	$V_{(BR)CEO}$	I_C=1mA, I_B=0	40			V
Emitter-base breakdown voltage	$V_{(BR)EBO}$	I_E=10μA, I_C=0	6			V
Collector cut-off current	I_{CEX}	V_{CE}=30V, $V_{EB(off)}$=3V			50	nA
Emitter cut-off current	I_{EBO}	V_{EB}=5V, I_C=0			100	nA
DC current gain	$h_{FE(1)}$	V_{CE}=1V, I_C=1mA	70		300	
	$h_{FE(2)}$	V_{CE}=1V, I_C=10mA	100			
	$h_{FE(3)}$	V_{CE}=1V, I_C=50mA	60			
Collector-emitter saturation voltage	$V_{CE(sat)}$	I_C=10mA, I_B=1mA			0.2	V
		I_C=50mA, I_B=5mA			0.3	V
Collector-emitter saturation voltage	$V_{BE(sat)}$	I_C=10mA, I_B=1mA	0.65		0.85	V
		I_C=50mA, I_B=5mA			0.95	V
Transition frequency	f_T	V_{CE}=20V,I_C=10mA, f=100MHz	300			MHz
Collector output capacitance	C_{ob}	V_{CB}=5V, I_E=0, f=1MHz			4	pF
Base input capacitance	C_{ib}	V_{EB}=0.5V, I_C=0, f=1MHz			8	pF
Delay time	t_d	V_{CC}=3V, $V_{BE(off)}$=-0.5V I_C=10mA, I_{B1}=1mA			35	ns
Rise time	t_r	V_{CC}=3V, $V_{BE(off)}$=-0.5V I_C=10mA, I_{B1}=1mA			35	ns
Storage time	t_s	V_{CC}=3V, I_C=10mA, I_{B1}= I_{B2}=1mA			200	ns
Fall time	t_f	V_{CC}=3V, I_C=10mA, I_{B1}= I_{B2}=1mA			50	ns

RATING AND CHARACTERISTIC CURVES

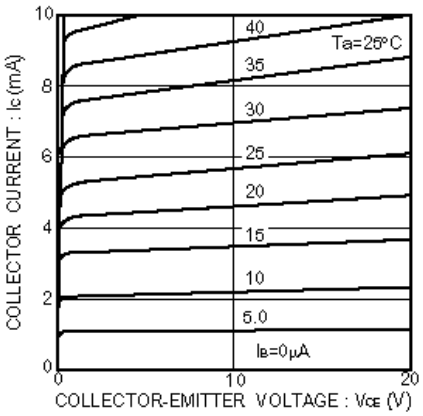


Fig.1 Grounded emitter output characteristics

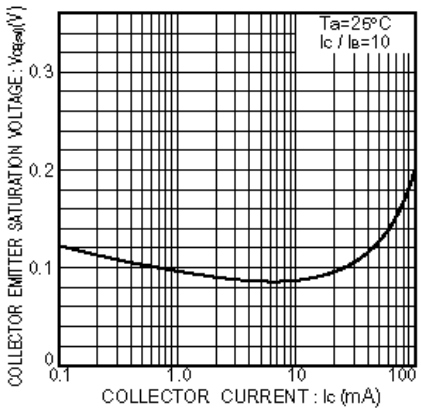


Fig.2 Collector-emitter saturation voltage vs. collector current

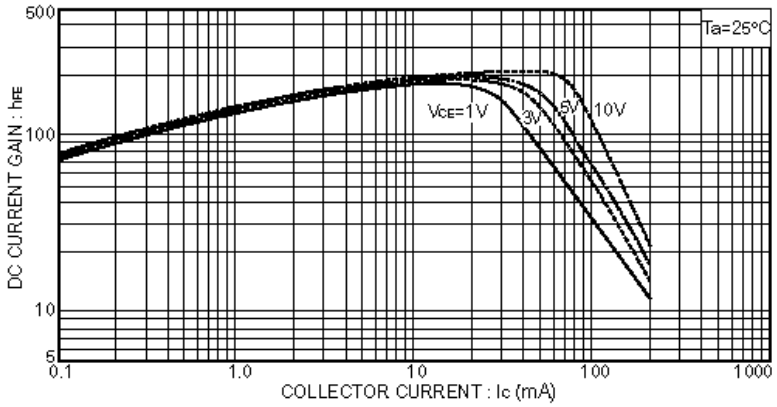


Fig.3 DC current gain vs. collector current (I)

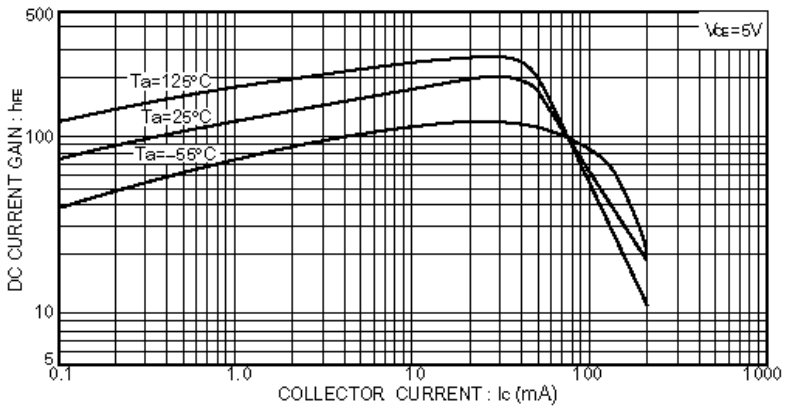


Fig.4 DC current gain vs. collector current (II)

RATING AND CHARACTERISTIC CURVES

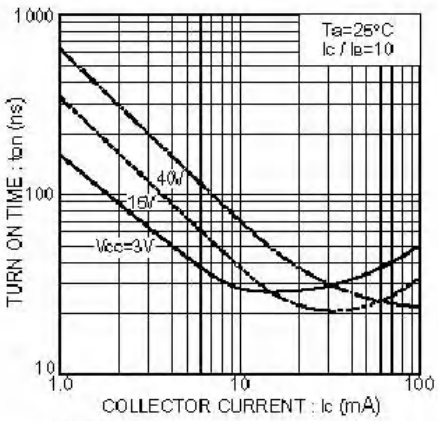


Fig.5 Turn-on time vs. collector current

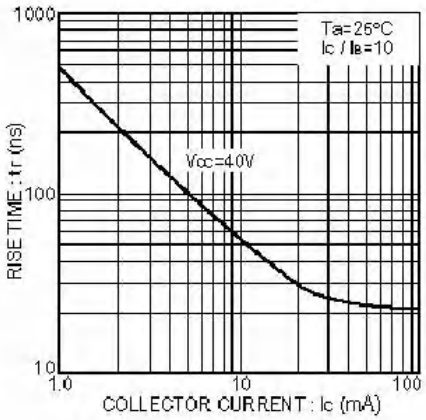


Fig.6 Rise time vs. collector current

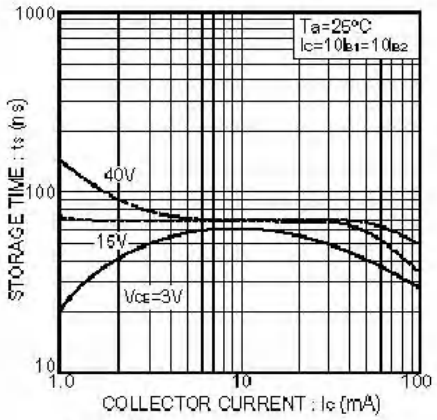


Fig.7 Storage time vs. collector current

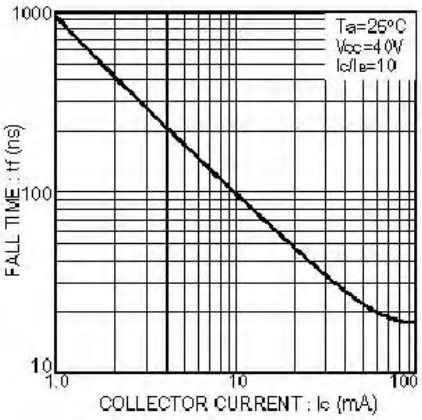


Fig.8 Fall time vs. collector current

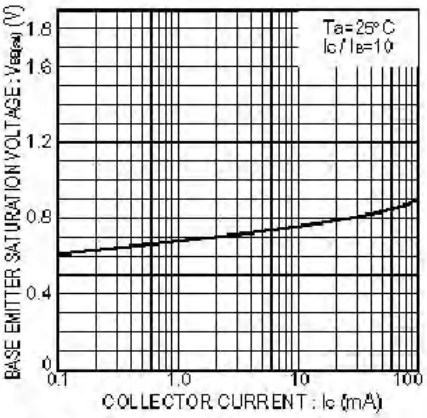


Fig.9 Base-emitter saturation voltage vs. collector current

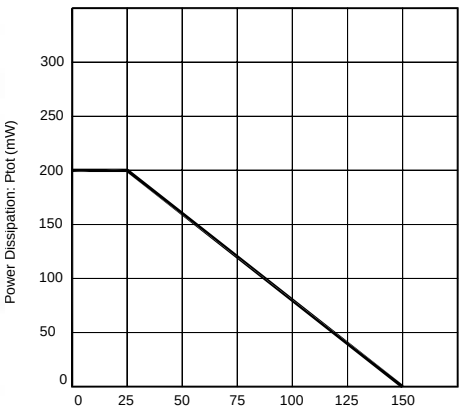
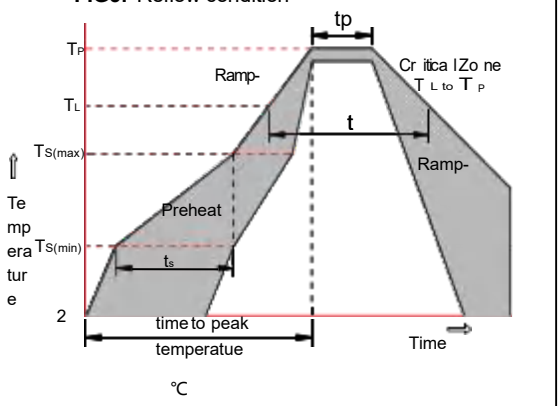


Fig.10 Power Dissipation vs Ambient Temperature

Soldering parameters

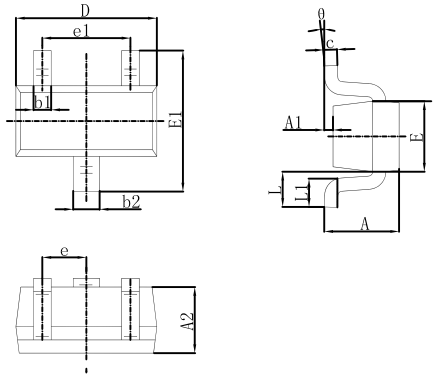
Reflow Condition		Pb-Free assembly (see as bellow)
Pre Heat	-Temperature Min ($T_{s(min)}$)	+150℃
	-Temperature Max($T_{s(max)}$)	+200℃
	-Time (Min to Max) (ts)	60-180 secs.
Average ramp up rate (Liquid us Temp (T_L) to peak)		3℃/sec. Max
$T_{s(max)}$ to T_L - Ramp-up Rate		3℃/sec. Max
Reflow	-Temperature(T_L)(Liquid us)	+217℃
	-Temperature(t_L)	60-150 secs.
Peak Temp (T_p)		+260(+0/-5)℃
Time within 5℃ of actual Peak Temp (t_p)		30 secs. Max
Ramp-down Rate		6℃/sec. Max
Time 25℃ to Peak Temp (T_P)		8 min. Max
Do not exceed		+260℃

FIG5: Reflow condition



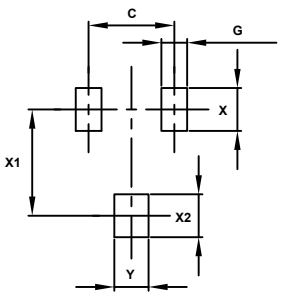
Package Dimensions & Suggested Pad Layout

SOT-523



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	0.700	0.900	0.028	0.035
A1	0.000	0.100	0.000	0.004
A2	0.700	0.800	0.028	0.031
b1	0.150	0.250	0.006	0.010
b2	0.250	0.350	0.010	0.014
c	0.100	0.200	0.004	0.008
D	1.500	1.700	0.059	0.067
E	0.700	0.900	0.028	0.035
E1	1.450	1.750	0.057	0.069
e	0.500 TYP.		0.020 TYP.	
e1	0.900	1.100	0.035	0.043
L	0.400 REF.		0.016 REF.	
L1	0.260	0.460	0.010	0.018
θ	0°	8°	0°	8°

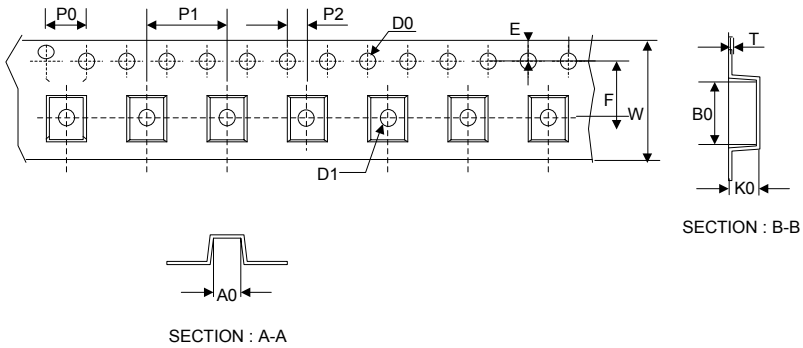
Dimensions in inches and (millimeters)



Dimensions	Value (in mm)
C	1.00
G	0.45
X	0.70
X1	1.40
X2	0.70
Y	0.60

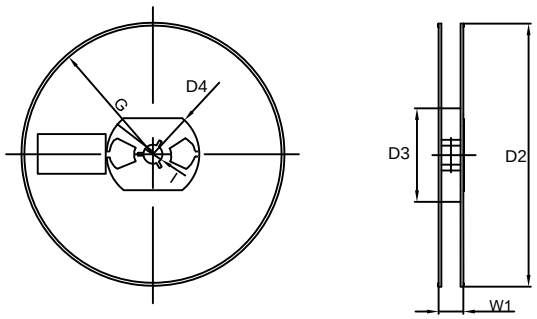
Tape & rell specification

Tape



Symbol	Dimension (mm)
P0	4.00±0.20
P1	4.00±0.20
P2	2.00±0.20
D0	1.55±0.20
D1	0.65±0.20
E	1.55±0.25
F	3.60±0.20
W	8.00±0.20
A0	2.10±0.20
B0	2.20±0.20
K0	1.10±0.20
T	0.20±0.20

7” Reel



D2	177.0±5.0
D3	55Min.
D4	R24.6±2.0
G	R82.0±2.0
I	13.0±2.0
W1	10.20±3.0

Quantity: 3000PCS